

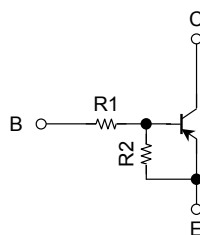
TOSHIBA Transistor Silicon PNP Epitaxial Type (PCT Process) (Bias Resistor Built-in Transistor)

RN2701JE,RN2702JE,RN2703JE RN2704JE,RN2705JE,RN2706JE

Switching, Inverter Circuit, Interface Circuit and
Driver Circuit Applications

- Two devices are incorporated into an Extreme-Super-Mini (5-pin) package.
- Incorporating a bias resistor into a transistor reduces parts count.
Reducing the parts count enables the manufacture of ever more compact equipment and lowers assembly cost.
- Complementary to RN1701JE~RN1706JE

Equivalent Circuit and Bias Resistor Values



Type No.	R1 (kΩ)	R2 (kΩ)
RN2701JE	4.7	4.7
RN2702JE	10	10
RN2703JE	22	22
RN2704JE	47	47
RN2705JE	2.2	47
RN2706JE	4.7	47

1.BASE1 (B1)	
2.EMITTER (E)	
3.BASE2 (B2)	
4.COLLECTOR2 (C2)	
5.COLLECTOR1 (C1)	
ESV	
JEDEC	—
JEITA	—
TOSHIBA	2-2P1D

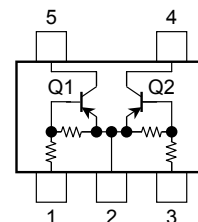
Weight: 0.003 g (typ.)

Maximum Ratings (Ta = 25°C) (Q1, Q2 common)

Characteristics	Symbol	Rating	Unit
Collector-base voltage	RN2701JE~2706JE V_{CBO}	-50	V
Collector-emitter voltage	V_{CEO}	-50	V
Emitter-base voltage	RN2701JE~2704JE RN2705JE, RN2706JE V_{EBO}	-10 -5	V
Collector current	I_C	-100	mA
Collector power dissipation	RN2701JE~2706JE P_C (Note)	100	mW
Junction temperature	T_j	150	°C
Storage temperature range	T_{stg}	-55~150	°C

Note: Total rating

Equivalent Circuit (top view)



Electrical Characteristics (Ta = 25°C) (Q1, Q2 common)

Characteristics		Symbol	Test Condition	Min	Typ.	Max	Unit
Collector cut-off current	RN2701JE~2706JE	I_{CBO}	$V_{CB} = -50\text{ V}, I_E = 0$	—	—	-100	nA
		I_{CEO}	$V_{CE} = -50\text{ V}, I_B = 0$	—	—	-500	
Emitter cut-off current	RN2701JE	I_{EBO}	$V_{EB} = -10\text{ V}, I_C = 0$	-0.82	—	-1.52	mA
	RN2702JE			-0.38	—	-0.71	
	RN2703JE			-0.17	—	-0.33	
	RN2704JE			-0.082	—	-0.15	
	RN2705JE	I_{EBO}	$V_{EB} = -5\text{ V}, I_C = 0$	-0.078	—	-0.145	
	RN2706JE			-0.074	—	-0.138	
DC current gain	RN2701JE	h_{FE}	$V_{CE} = -5\text{ V}, I_C = -10\text{ mA}$	30	—	—	
	RN2702JE			50	—	—	
	RN2703JE			70	—	—	
	RN2704JE			80	—	—	
	RN2705JE			80	—	—	
	RN2706JE			80	—	—	
Collector-emitter saturation voltage	RN2701JE~2706JE	$V_{CE(sat)}$	$I_C = -5\text{ mA}, I_B = -0.25\text{ mA}$	—	-0.1	-0.3	V
Input voltage (ON)	RN2701JE	$V_{I(ON)}$	$V_{CE} = -0.2\text{ V}, I_C = -5\text{ mA}$	-1.1	—	-2.0	V
	RN2702JE			-1.2	—	-2.4	
	RN2703JE			-1.3	—	-3.0	
	RN2704JE			-1.5	—	-5.0	
	RN2705JE			-0.6	—	-1.1	
	RN2706JE			-0.7	—	-1.3	
Input voltage (OFF)	RN2701JE~2704JE	$V_{I(OFF)}$	$V_{CE} = -5\text{ V}, I_C = -0.1\text{ mA}$	-1.0	—	-1.5	V
	RN2705JE, 2706JE			-0.5	—	-0.8	
Transition frequency	RN2701JE~2706JE	f_T	$V_{CE} = -10\text{ V}, I_C = -5\text{ mA}$	—	200	—	MHz
Collector output capacitance	RN2701JE~2706JE	C_{ob}	$V_{CB} = -10\text{ V}, I_E = 0, f = 1\text{ MHz}$	—	3	6	pF
Input resistor	RN2701JE	R1	—	3.29	4.7	6.11	kΩ
	RN2702JE			7	10	13	
	RN2703JE			15.4	22	28.6	
	RN2704JE			32.9	47	61.1	
	RN2705JE			1.54	2.2	2.86	
	RN2706JE			3.29	4.7	6.11	
Resistor ratio	RN2701JE~2704JE	R1/R2	—	0.9	1.0	1.1	
	RN2705JE			0.0421	0.0468	0.0515	
	RN2706JE			0.09	0.1	0.11	

